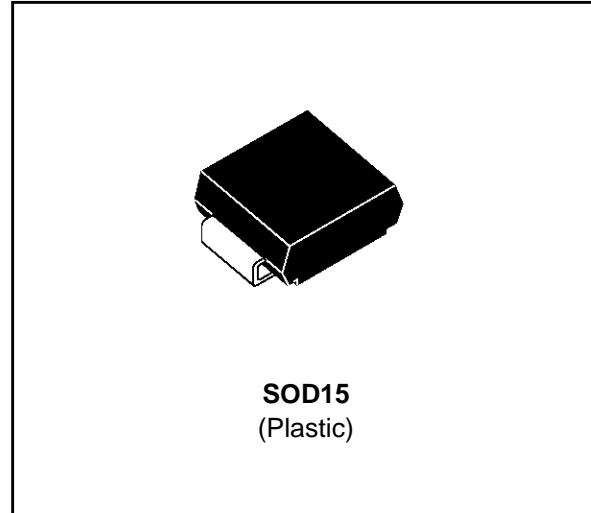


FAST RECOVERY RECTIFIER DIODES
FEATURES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING
- SURFACE MOUNT DEVICE


DESCRIPTION

Single high voltage rectifier ranging from 200V to 400 V suited for Switch Mode Power Supplies and other power converters.

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | | Value | Unit |
|--------------------|-------------------------------------------|--------------------------------------------|--------------------------------|------------------------------------------|
| $I_{F(RMS)}$ | RMS forward current | | 10 | A |
| $I_{F(AV)}$ | Average forward current | $T_I=55^{\circ}\text{C}$ $\delta = 0.5$ | 3 | A |
| I_{FSM} | Non repetitive surge peak forward current | $t_p=10\text{ms}$ sinusoidal | 60 | A |
| T_{stg} T_j | Storage and junction temperature range | | - 40 to + 150 - 40 to + 150 | $^{\circ}\text{C}$ $^{\circ}\text{C}$ |

| Symbol | Parameter | SMBYT03- | | | Unit |
|-----------|---------------------------------|----------|-----|-----|------|
| | | 200 | 300 | 400 | |
| V_{RRM} | Repetitive peak reverse voltage | 200 | 300 | 400 | V |

THERMAL RESISTANCE

| Symbol | Parameter | Value | Unit |
|---------------|----------------|-------|----------------------|
| $R_{th(j-l)}$ | Junction-leads | 20 | $^{\circ}\text{C/W}$ |

SMBYT03

ELECTRICAL CHARACTERISTICS STATIC CHARACTERISTICS

| Symbol | Test Conditions | | Min. | Typ. | Max. | Unit |
|----------|---------------------------|--------------------|------|------|------|---------------|
| V_F * | $T_j = 25^\circ\text{C}$ | $I_F = 3\text{ A}$ | | | 1.5 | V |
| | $T_j = 100^\circ\text{C}$ | | | | 1.4 | |
| I_R ** | $T_j = 25^\circ\text{C}$ | $V_R = V_{RRM}$ | | | 20 | μA |
| | $T_j = 100^\circ\text{C}$ | | | | 0.5 | mA |

Pulse test : * $t_p = 380\ \mu\text{s}$, duty cycle < 2 %

** $t_p = 5\ \text{ms}$, duty cycle < 2 %

RECOVERY CHARACTERISTICS

| Symbol | Test Conditions | | Min. | Typ. | Max. | Unit |
|--------|--------------------------|-----------------------------------------------------------------------------|------|------|------|------|
| trr | $T_j = 25^\circ\text{C}$ | $I_F = 0.5\text{A}$ $I_{rr} = 0.25\text{A}$ $I_R = 1\text{A}$ | | | 25 | ns |
| | | $I_F = 1\text{A}$ $dI_F/dt = -15\text{A}/\mu\text{s}$ $V_R = 30\text{V}$ | | | 60 | |

TURN-OFF SWITCHING CHARACTERISTICS (Without serie inductance)

| Symbol | Test Conditions | | Min. | Typ. | Max. | Unit |
|-----------|-----------------------------------------------------|---------------------------------------------------------------------------------------|------|------|------|------|
| t_{fRM} | $V_{CC} = 200\text{V}$ $T_j = 100^\circ\text{C}$ | $I_F = 3\text{A}$ $L_p \leq 0.05\ \mu\text{H}$ $dI_F/dt = -50\text{A}/\mu\text{s}$ | | 35 | 50 | ns |
| I_{RM} | | | | 1.5 | 2 | A |

To evaluate the conduction losses use the following equation :

$$P = 1.1 \times I_{F(AV)} + 0.08 \times I_{F(RMS)}^2$$

| | | | |
|--------------------|-----|-----|-----|
| Voltage (V) | 200 | 300 | 400 |
| Marking | C2 | C3 | C4 |

Laser marking
Logo indicates cathode

Fig.1 : Low frequency power losses versus average current.

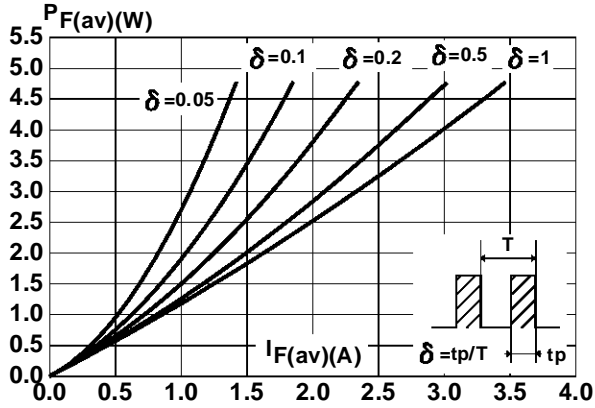


Fig.2 : Peak current versus form factor.

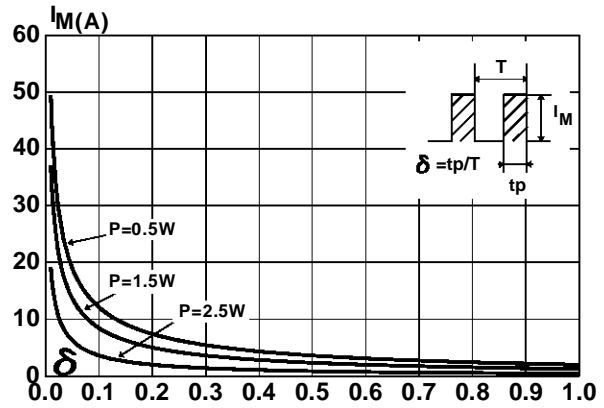


Fig.3 : Non repetitive surge peak forward current versus overload duration.

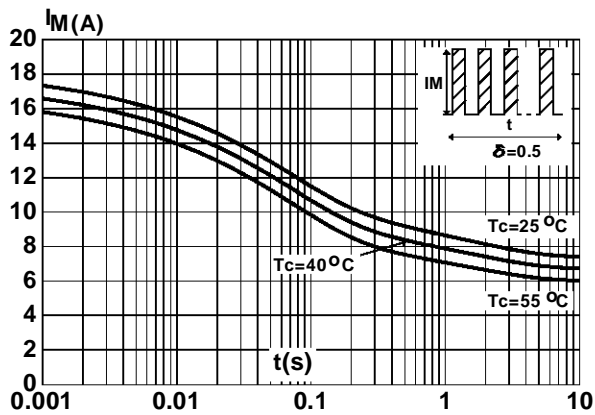


Fig.4 : Relative variation of thermal impedance junction to lead versus pulse duration.

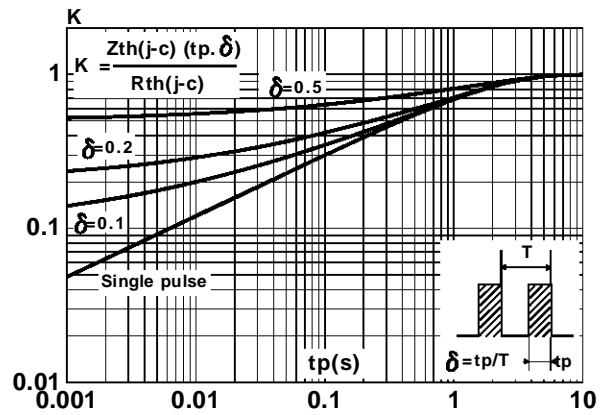


Fig.5 : Voltage drop versus forward current. (Maximum values)

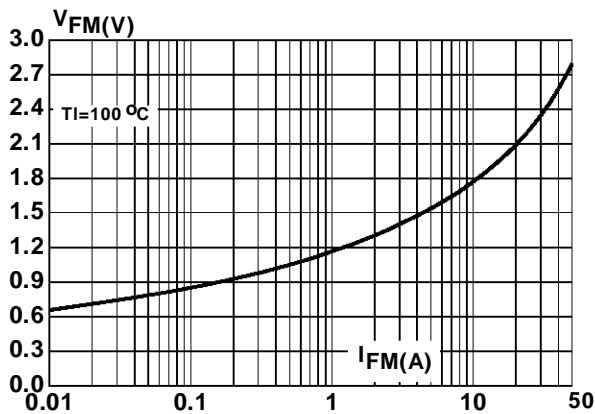


Fig.6 : Average current versus ambient temperature. (duty cycle : 0.5)

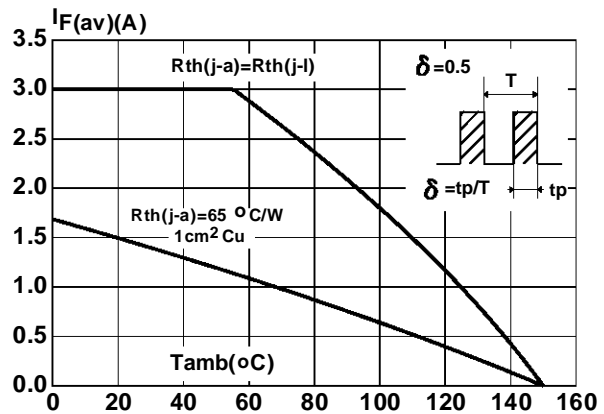


Fig.7 : Recovery time versus di_F/dt .

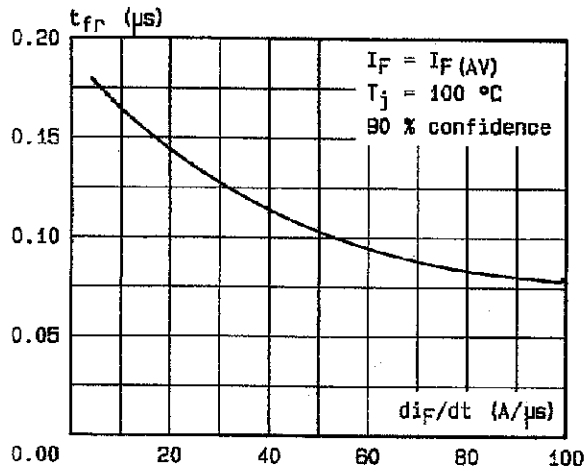


Fig.9 : Peak reverse current versus di_F/dt .

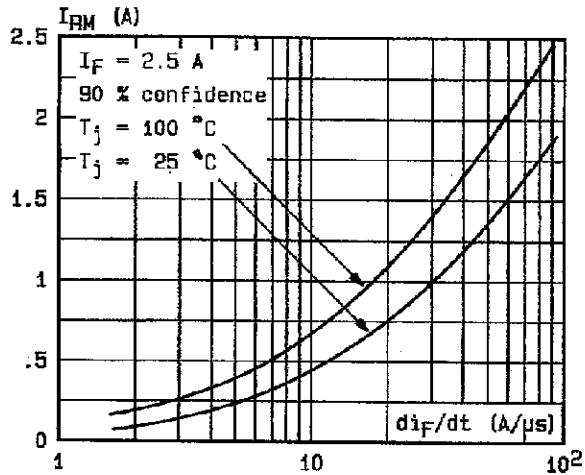


Fig.11 : Dynamic parameters versus junction temperature.

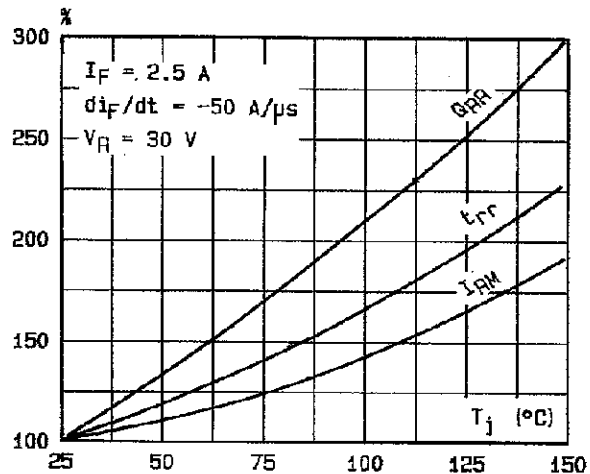


Fig.8 : Peak forward voltage versus di_F/dt .

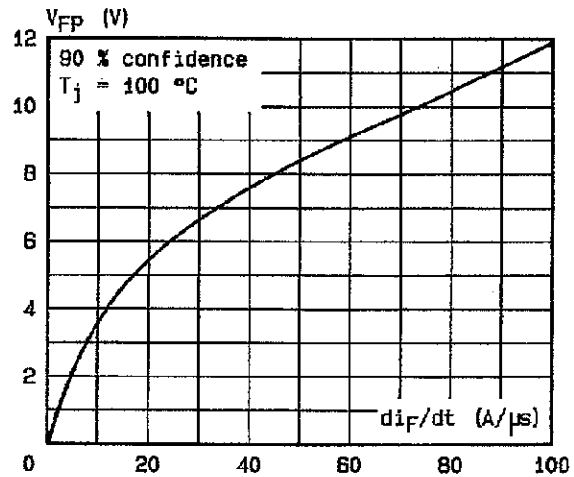


Fig.10 : Recovery charge versus di_F/dt . (typical values)

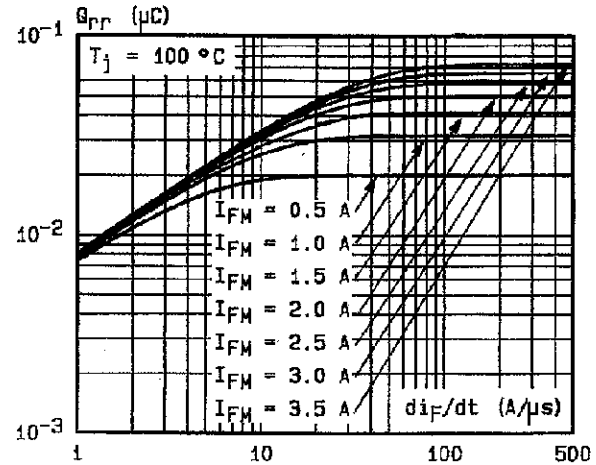
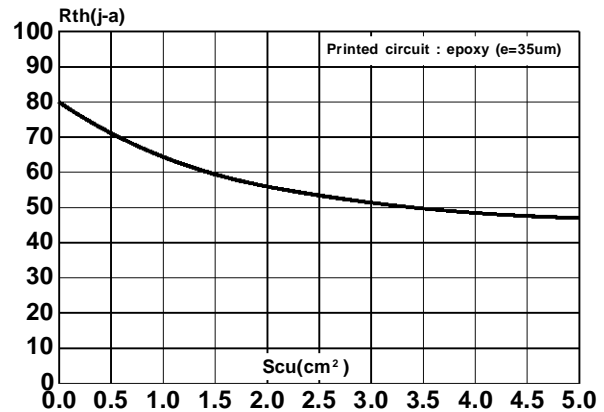
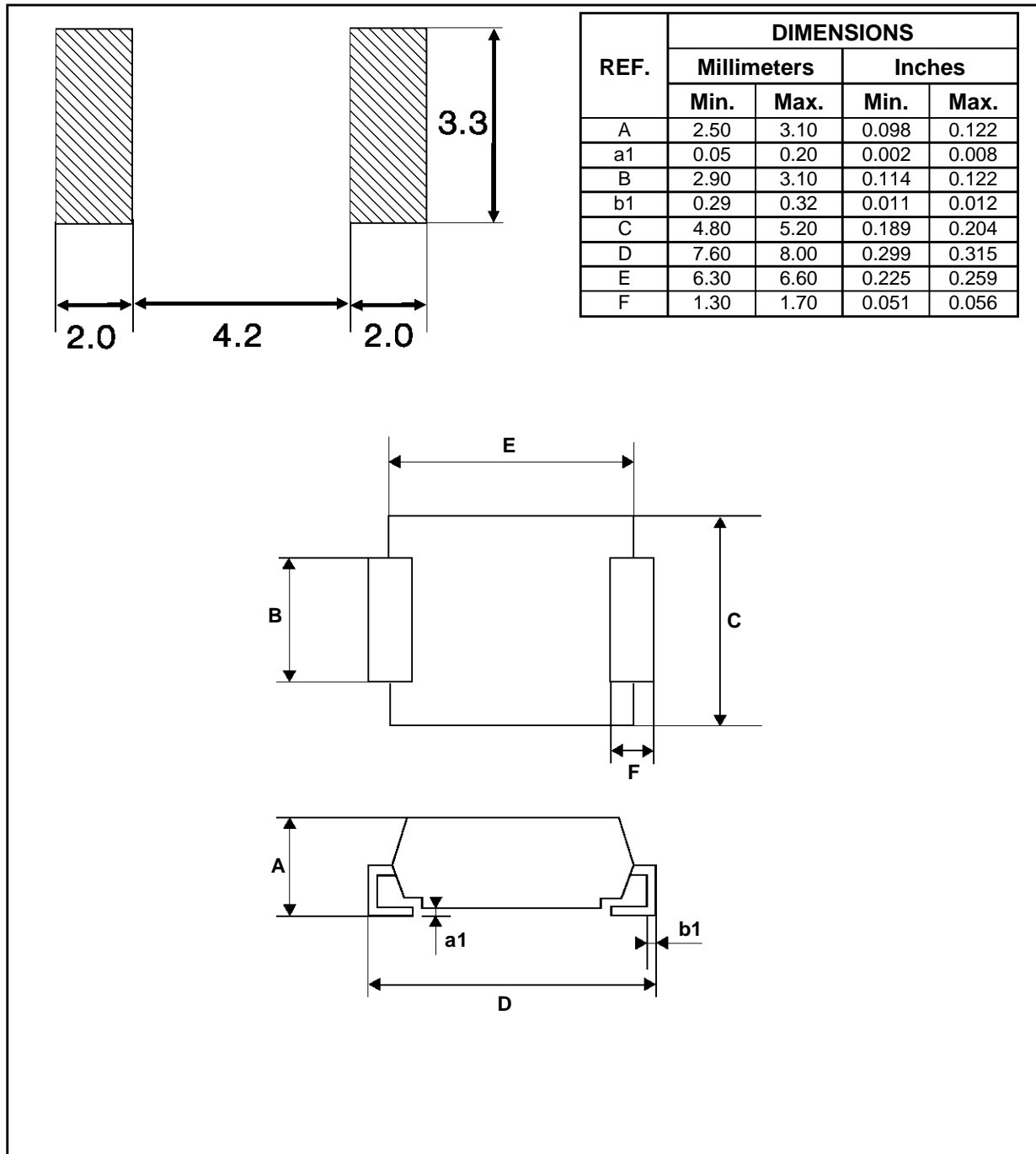


Fig.12 : Thermal resistance junction to ambient versus copper surface under each lead.



PACKAGE MECHANICAL DATA
SOD15



Laser Marking
Logo indicated cathode

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